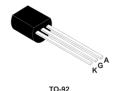


0.8 A 400 V high immunity sensitive SCR thyristor in TO-92





Features

- On-state rms current, I_{T(RMS)} 0.8 A
- 125 °C max. T_i
- Low 0.2 mA gate current
- Repetitive peak off-state voltage, V_{DRM/VRRM} 400 V
- ECOPACK2 compliant

Applications

- Gate driver for large Thyristors
- · Overvoltage crowbar protection
- · Ground fault circuit interrupters
- · Arc fault circuit interrupter
- Standby mode power supplies
- · Residual current detector

Description

Thanks to highly sensitive triggering levels, the 0.8 A P0102DA SCR thyristor is suitable for all applications where available gate current is limited.

This device offers a high blocking voltage of 400 V, ideal for applications like interrupters circuits.

The P0102DA is available in through-hole TO-92 package.

Product status link	
P0102DA	

Product summary			
I _{T(RMS)}	0.8 A		
V_{DRM}/V_{RRM}	400 V		
I _{GT}	0.2 mA		
T _j max.	125 °C		



1 Characteristics

Table 1. Absolute maximum ratings (limiting values)

Symbol	Parameters	Value	Unit		
I _{T(RMS)}	On-state RMS current (180° conduction angle)				Α
I _{T(AV)}	Average on-state current (180° conduction angle)		T _L = 55 °C	0.5	Α
I	Non repetitive surge peak on-state current,	$t_p = 8.3 \text{ ms}$	T _i = 25 °C	8	А
I _{TSM}	T _j initial = 25 °C	t _p = 10 ms	- 1j - 25 C	7	
I ² t	I ² t value for fusing	T _j = 25 °C	0.24	A ² s	
dl/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \le 100 \text{ ns}$ $T_j = 2 \times I_{GT}$		T _j = 25 °C	50	A/µs
V _{DRM} / V _{RRM}	Repetitive peak off-state voltage T_j = 125 °C				V
I _{GM}	Peak gate current $t_p = 20 \mu s$ $T_j = 125 °C$		1	А	
P _{G(AV)}	Average gate power dissipation	0.1	W		
T _{stg}	Storage junction temperature range				°C
Tj	Operating junction temperature range			-40 to +125	°C

Table 2. Electrical characteristics (T_j = 25 °C, unless otherwise specified)

Symbol	Parameters		Value	Unit
I _{GT}	V 12 V P 33 O	Max.	200	μA
V _{GT}	$V_D = 12 \text{ V}, R_L = 33 \Omega$		0.8	V
$V_{\sf GD}$	$_{\rm D}$ = $V_{\rm DRM}$, $R_{\rm L}$ = 3.3 k Ω , $R_{\rm GK}$ = 1 k Ω , $T_{\rm j}$ = 125 °C		0.1	V
V _{RG}	I _{RG} = 10 μA	Min.	8	
lн	I_T = 50 mA, R_{GK} = 1 k Ω	Max.	5	mA
IL	$I_G = 1.2 I_{GT}$, $R_{GK} = 1 k\Omega$	Max.	6	mA
dV/dt	$V_D = 67 \% V_{DRM}, R_{GK} = 1 k\Omega, T_j = 125 °C$	Min.	75	V/µs

Table 3. Static electrical characteristics

Symbol	Test conditions			Value	Unit
V _T	$I_{TM} = 1.6 \text{ A}, t_p = 380 \mu\text{s}$		Max.	1.95	V
V _{TO}	Threshold on-state voltage	125 °C	Max.	0.95	V
R _d	Dynamic resistance	125 °C	Max.	600	mΩ
I _{DRM}	$V_D = V_{DRM}$	25 °C	Max.	1	μΑ
I _{RRM}	$V_R = V_{RRM}$		iviax.	0.1	mA

DS13119 - Rev 2 page 2/9



Table 4. Thermal resistance

Symbol	Parameters Parameters	Max. value	Unit
R _{th(j-l)}	Junction to lead (DC)	80	°C/W
R _{th(j-a)}	Junction to ambient (DC)	150	C/VV

DS13119 - Rev 2 page 3/9



1.1 Characteristics (curves)

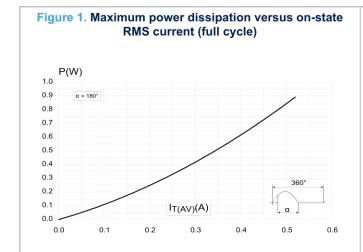
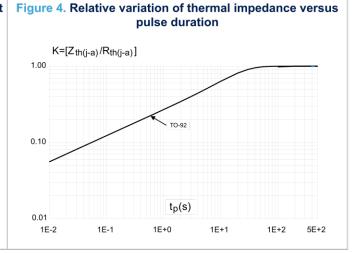
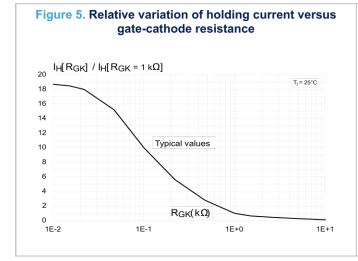
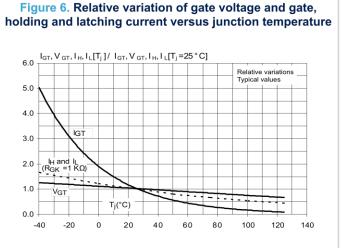


Figure 2. Average and DC on-state current versus lead temperature $I_{T(AV)}(A)$ 1.0 0.9 0.8 D.C. (TO-92) 0.7 0.6 0.5 0.4 0.3 α = 180° (TO-92) 0.2 0.1 T_{lead}(°C) 0.0 25 50 75 100 125

Figure 3. Average and DC on-state current versus ambient temperature $I_{T(AV)}(A)$ 1.2 1.1 1.0 0.9 8.0 0.7 D.C. (TO-92) 0.6 0.5 0.4 0.3 $\alpha = 180^{\circ} (TO-92)$ 0.2 0.1 T_{amb}(°C) 0.0 100







DS13119 - Rev 2 page 4/9



Figure 7. Relative variation of static dV/dt immunity versus gate-cathode resistance

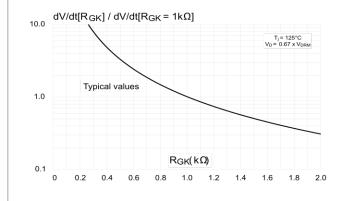


Figure 8. Relative variation of dV/dt immunity versus gatecathode capacitance

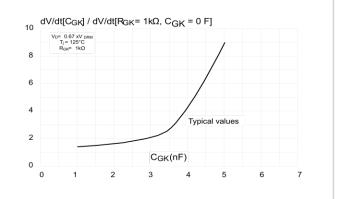


Figure 9. Surge peak on-state current versus number of cycles

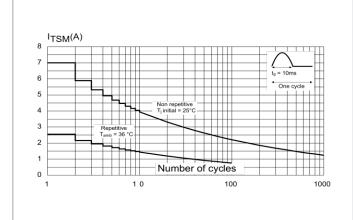


Figure 10. Non-repetitive surge peak on-state current for sinusoidal pulse (t_p< 10 ms)

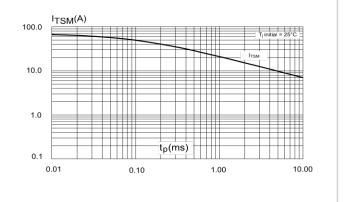
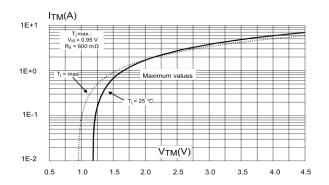


Figure 11. On-state characteristics (maximum values)



DS13119 - Rev 2 page 5/9



2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

2.1 TO-92 package information

- Lead free plating + halogen-free molding resin
- Epoxy meets UL94, V0

Figure 12. TO-92 package outline

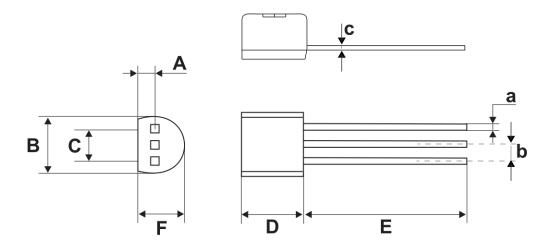


Table 5. TO-92 package mechanical data

				Dimensions			
Ref.		Millimeters		Inches ⁽¹⁾			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
А		1.35			0.0531		
В			4.70			0.1850	
С		2.54			0.1000		
D	4.40			0.1732			
Е	12.70			0.5000			
F			3.70			0.1457	
а			0.50			0.0197	
b		1.27			0.0500		
С			0.48			0.0189	

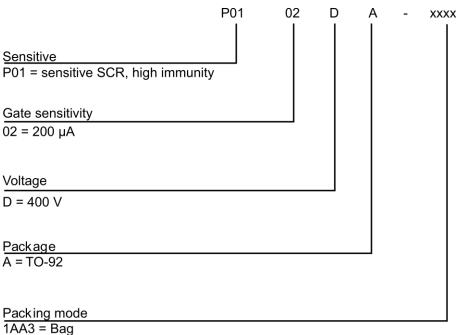
1. Inches dimensions given for information

DS13119 - Rev 2 page 6/9



Ordering information

Figure 13. Ordering information scheme



2AL3 = Ammopack

5AL3 = Tape and reel 13 inch

Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
P0102DA 1AA3				2500	Bag
P0102DA 2AL3	P0102 DA	TO-92	TO-92 0.22 g	2000	AMMOPACK not in dry bag
P0102DA 5AL3				2000	Tape and reel 13"

page 7/9



Revision history

Table 7. Document revision history

Date	Revision	Changes
14-Oct-2019	1	Initial release.
18-May-2020	2	Updated Section Cover image.

DS13119 - Rev 2 page 8/9



IMPORTANT NOTICE - PLEASE READ CAREFULLY

STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, enhancements, modifications, and improvements to ST products and/or to this document at any time without notice. Purchasers should obtain the latest relevant information on ST products before placing orders. ST products are sold pursuant to ST's terms and conditions of sale in place at the time of order acknowledgement.

Purchasers are solely responsible for the choice, selection, and use of ST products and ST assumes no liability for application assistance or the design of Purchasers' products.

No license, express or implied, to any intellectual property right is granted by ST herein.

Resale of ST products with provisions different from the information set forth herein shall void any warranty granted by ST for such product.

ST and the ST logo are trademarks of ST. For additional information about ST trademarks, please refer to www.st.com/trademarks. All other product or service names are the property of their respective owners.

Information in this document supersedes and replaces information previously supplied in any prior versions of this document.

© 2020 STMicroelectronics - All rights reserved

DS13119 - Rev 2 page 9/9